

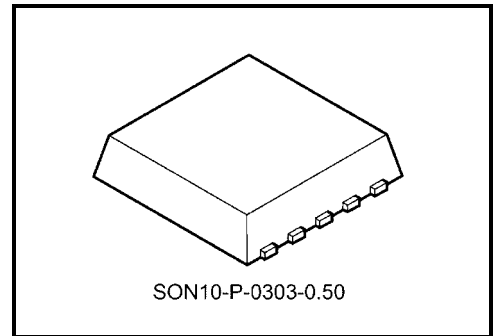
TA6009FM

Shock Sensor IC (1 ch version)

TA6009FM detects an existence of external shock through the shock sensor and output.

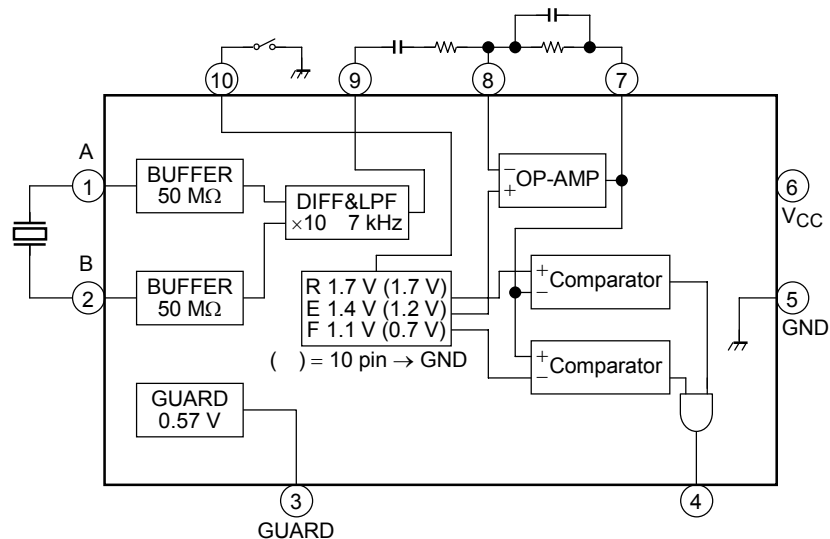
Features

- TA6009FM operates from 2.7 to 5.5 V DC single power supply voltage.
- Signal from the shock sensor is amplified according to setting gain, and is detected through the internal window comparator.
- TA6009FM incorporates 1-ch shock detecting circuitry.
- Input terminal of sensor signal is designed high impedance.
Differential input impedance = 100 MΩ (typ.)
- LPF (Low Pass Filter) circuitry is incorporated.
Cut-off frequency of LPF = 7 kHz
- Sensitivity of shock detection can be adjusted by external devices.
- Small package
SON10-P-0303-0.50 (0.5 mm pitch)

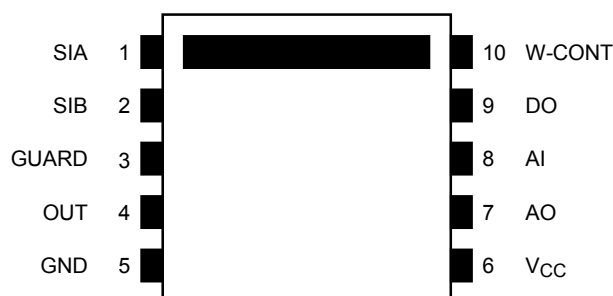


Weight: 0.016 g (typ.)

Block Diagram



Pin Connection (top view)



Pin Function

| Pin No. | Pin Name | Function |
|---------|-----------------|--|
| 1 | SIA | Connection terminal of shock sensor |
| 2 | SIB | Connection terminal of shock sensor |
| 3 | GUARD | Input (1, 2 pin) GUARD terminal |
| 4 | OUT | Output terminal (output = "L" when shock is detected.) |
| 5 | GND | Ground terminal |
| 6 | V _{CC} | Power supply voltage |
| 7 | AO | Op-Amp output terminal |
| 8 | AI | Op-Amp input terminal |
| 9 | DO | Differential-Amp output terminal |
| 10 | W-CONT | WindComp. trip voltage selection terminal |

Maximum Ratings (Ta = 25°C)

| Characteristics | Symbol | Rating | Unit |
|----------------------|------------------|------------|------|
| Power supply voltage | V _{CC} | 7 | V |
| Power dissipation | P _D | 150 | mW |
| Storage temperature | T _{stg} | -55 to 150 | °C |

Recommend Operating Condition

| Characteristics | Symbol | Rating | Unit |
|-----------------------|------------------|------------|------|
| Power supply voltage | V _{CC} | 2.7 to 5.5 | V |
| Operating temperature | T _{opr} | -25 to 85 | °C |

Note: The IC may be destroyed due to short circuit between adjacent pins, incorrect orientation of device's mounting, connecting positive and negative power supply pins wrong way round, air contamination fault, or fault by improper grounding.

Electrical Characteristics (unless otherwise specified, $V_{CC} = 3.3\text{ V}$, $T_a = 25^\circ\text{C}$)

| Characteristics | Symbol | Test Circuit | Test Condition | Min | Typ. | Max | Unit |
|-----------------|----------|--------------|-------------------------|-----|------|-----|------|
| Supply voltage | V_{CC} | — | — | 2.7 | 3.3 | 5.5 | V |
| Supply current | I_{CC} | (1) | $V_{CC} = 3.3\text{ V}$ | | 1.8 | 2.4 | mA |
| | | | $V_{CC} = 5.0\text{ V}$ | | 1.8 | 2.4 | |

(GUARD)

| Characteristics | Symbol | Test Circuit | Test Condition | Min | Typ. | Max | Unit |
|-----------------|------------|--------------|----------------|------|------|------|------|
| Output voltage | V_{oGur} | (2) | — | 0.52 | 0.57 | 0.62 | V |

(DIFF-AMP)

| Characteristics | Symbol | Test Circuit | Test Condition | Min | Typ. | Max | Unit |
|-------------------------------|------------|--------------|--|------|------|------|---------------|
| Input impedance (Note 1) | Z_{in} | — | — | 50 | 100 | | $M\Omega$ |
| Gain | G_{vBuf} | (3) | — | 19.6 | 20 | 20.4 | dB |
| Output DC voltage | V_{oBuf} | (4) | Connect C = 100 pF between 1 pin and 2 pin | 0.7 | 1 | 1.3 | V |
| Low pass filter cut-off freq. | f_c | (5) | Frequency at -3dB point | 5 | 7 | 10 | kHz |
| Output source current | I_{Bso} | (6) | $V_{oh} = V_{CC} - 1\text{ V}$ | 400 | 800 | | μA |
| Output sink current | I_{Bsi} | (7) | $V_{ol} = 0.3\text{ V}$ | 75 | 130 | | μA |

Note 1: Marked parameters are reference data.

(OP-AMP)

| Characteristics | Symbol | Test Circuit | Test Condition | Min | Typ. | Max | Unit |
|----------------------------|-----------|--------------|--------------------------------|------|------|------|---------------|
| Cut-off frequency (Note 1) | f_T | — | — | 1.5 | 2 | | MHz |
| Openloop gain (Note 1) | G_{vo} | — | — | 80 | 90 | | dB |
| Input voltage 1 | V_{in1} | (8) | 10 pin → OPEN (Note 2) | 1.33 | 1.4 | 1.47 | V |
| Input voltage 2 | V_{in2} | (9) | 10 pin → GND (Note 2) | 1.14 | 1.2 | 1.26 | V |
| Input current | I_{in} | (10) | — | | 25 | 50 | nA |
| Offset voltage (Note 1) | V_{off} | — | — | -5 | 0 | 5 | mV |
| Output source current | I_{Aso} | (11) | $V_{oh} = V_{CC} - 1\text{ V}$ | 300 | 800 | | μA |
| Output sink current | I_{Asi} | (12) | $V_{ol} = 0.3\text{ V}$ | 130 | 200 | | μA |

Note 1: Marked parameters are reference data.

Note 2: 10 pin must be non-connected otherwise connected to GND.

(Window-comparator)

| Characteristics | Symbol | Test Circuit | Test Condition | Min | Typ. | Max | Unit |
|-------------------------|------------|--------------|----------------------------------|---------------------|-------------------|---------------------|---------------|
| Trip voltage 1 (Note 1) | V_{trp1} | — | 10 pin → OPEN (Note 2) | $V_{in1} \pm 0.285$ | $V_{in1} \pm 0.3$ | $V_{in1} \pm 0.315$ | V |
| Trip voltage 2 (Note 1) | V_{trp2} | — | 10 pin → GND (Note 2) | $V_{in2} \pm 0.475$ | $V_{in2} \pm 0.5$ | $V_{in2} \pm 0.525$ | V |
| Output source current | I_{Wso} | (13) | $V_{oh} = V_{CC} - 0.5\text{ V}$ | 30 | 50 | | μA |
| Output sink current | I_{Wsi} | (14) | $V_{ol} = 0.3\text{ V}$ | 300 | 800 | | μA |

Note 1: Marked parameters are reference data.

Note 2: 10 pin must be non-connected otherwise connected to GND.

Application Note

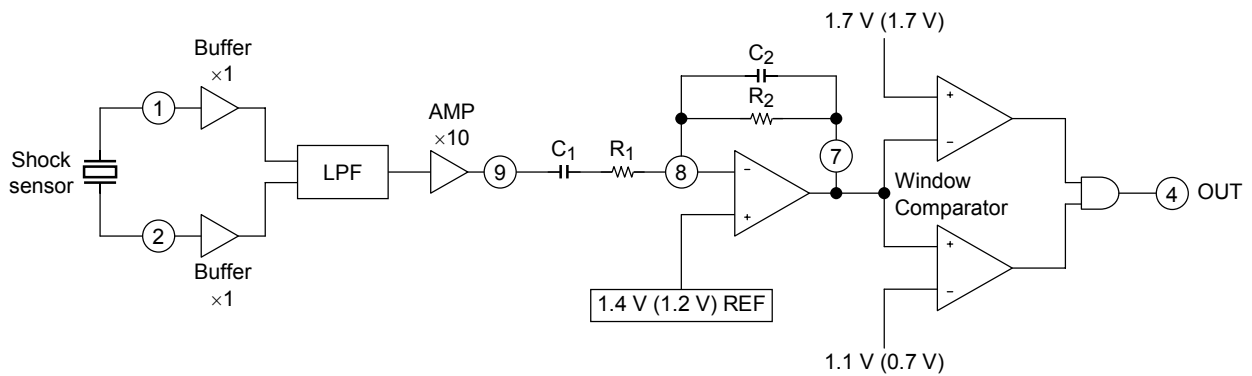


Figure 1 The configuration of G-force sensor amplifier

Figure 1 is the composition of G-Force sense amplifier.

The shock sensor is connected between 1 and 2 terminal.

When G-force Sensor (sensor sensibility = s (mV/G)) is used to detect external shock of g (G), the external parts are determined as following.

(Gain setting) * 10 PIN → GND

$$500/(s \times g) = G1$$

$$G1/10 = G \text{ (OP-AMP)}$$

(HPF setting)

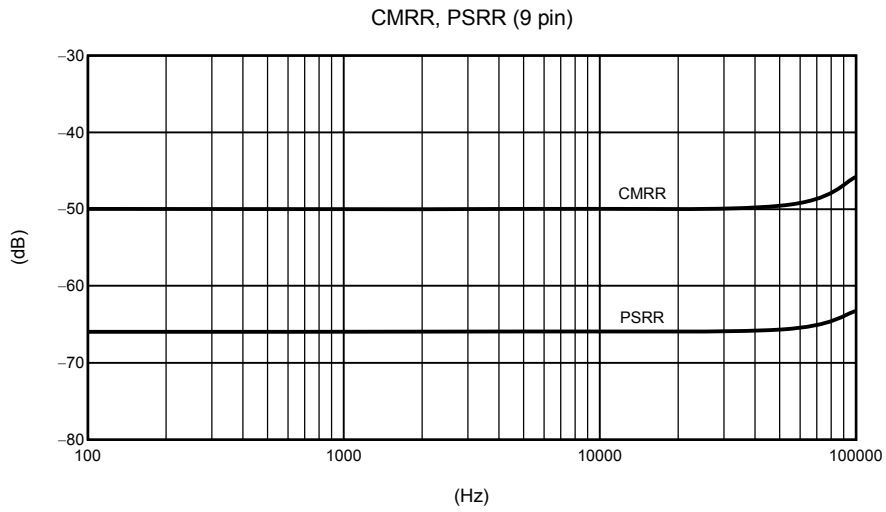
$$fc = 1/(2 \pi \times R1 \times C1)$$

(LPF setting)

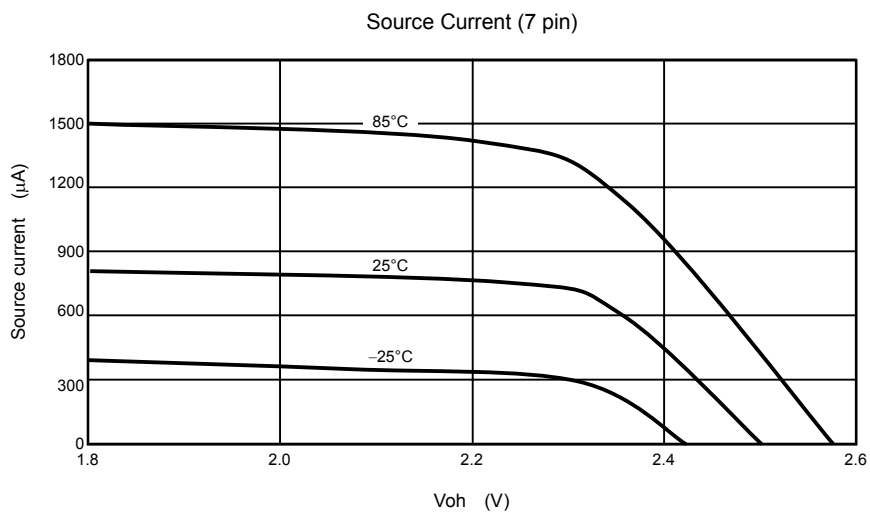
$$fc = 1/(2 \pi \times R2 \times C2)$$

Reference Data

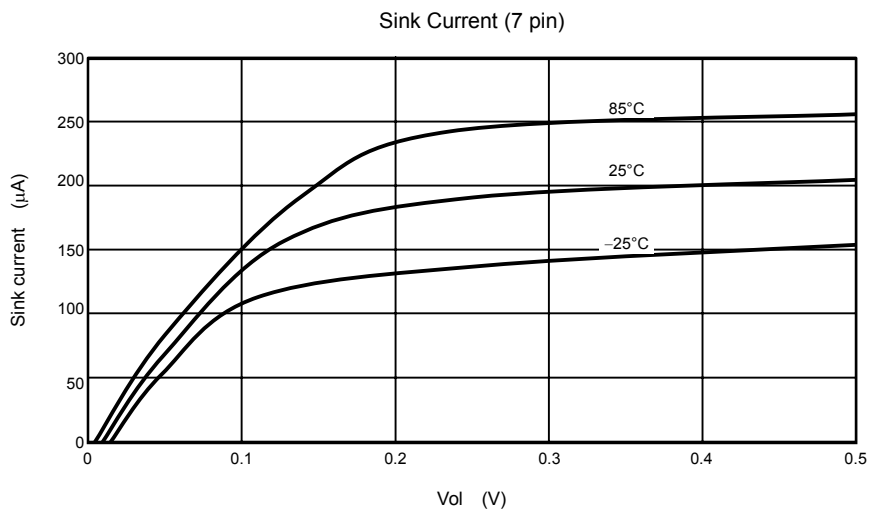
- (1) 9 pin (DIFF-AMP output) CMRR, PSRR



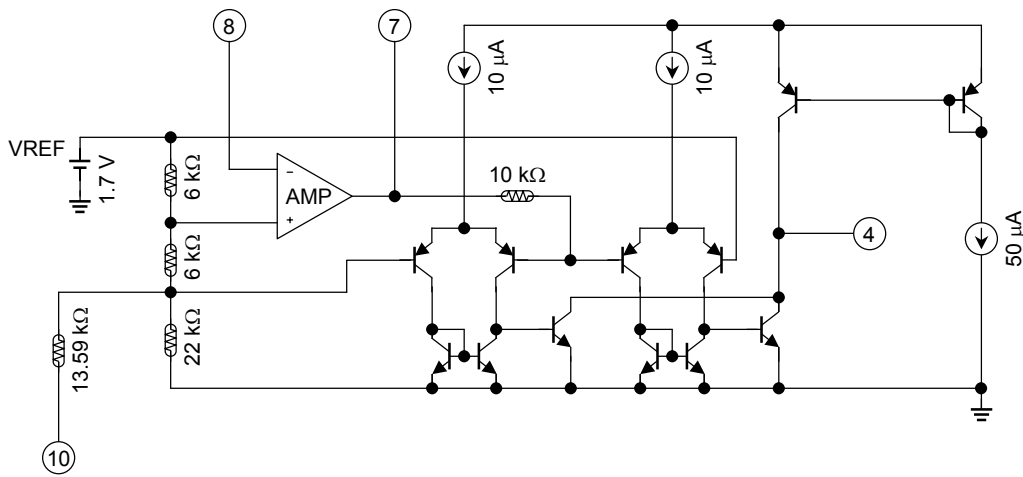
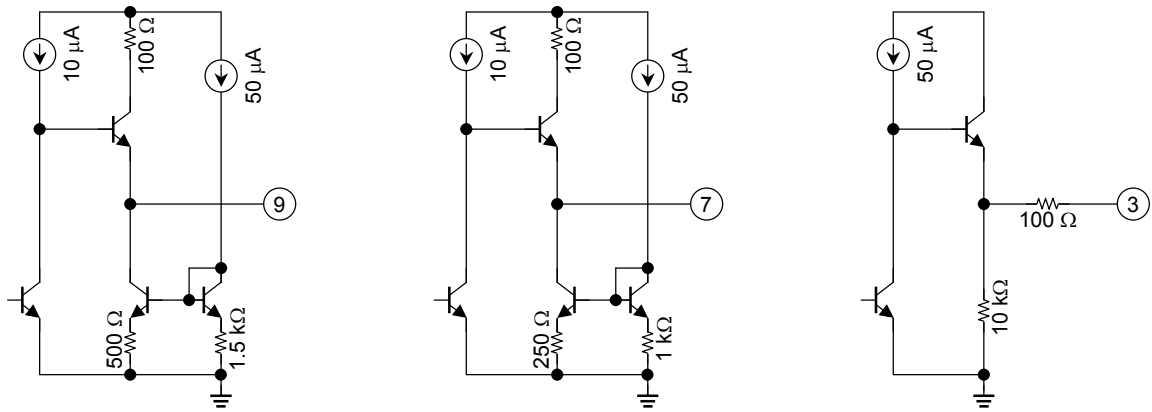
- (2) 7 pin (OP-AMP output) source current



- (3) 7 pin (OP-AMP output) sink current

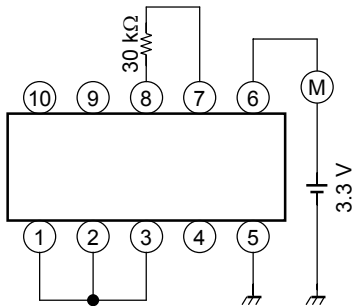


Equivalent Circuit

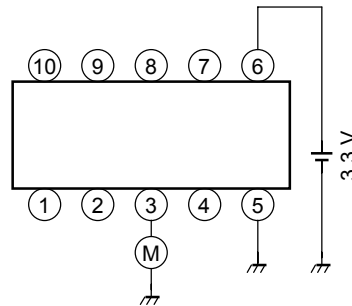


Test Circuit

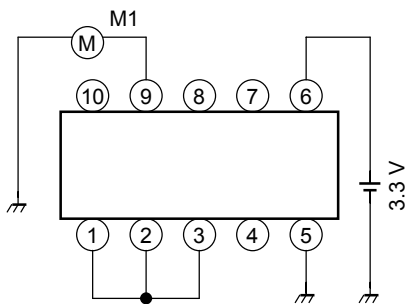
(1) Supply current **ICC**



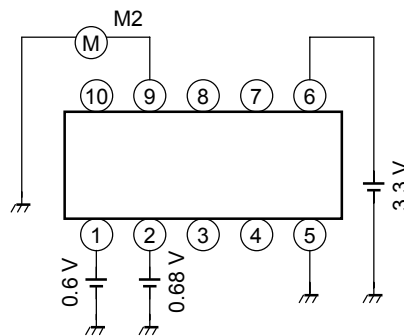
(2) GUARD
Output voltage **VoGur**



(3) DIFF-AMP
Gain **GvBuf**
Step 1

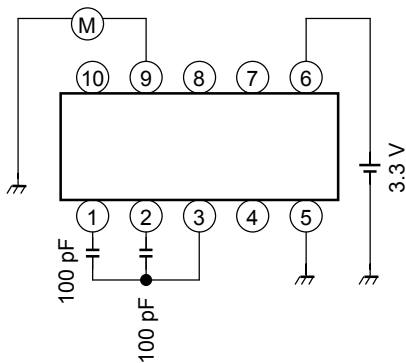


Step 2

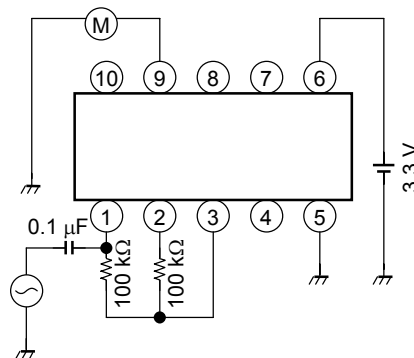


$$\text{Gain} = \frac{M2 - M1}{0.68 - 0.60}$$

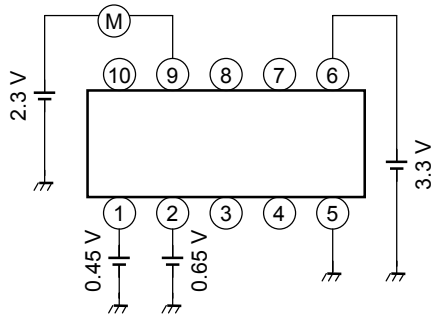
(4) DIFF-AMP
Output DC voltage **VoBuf**



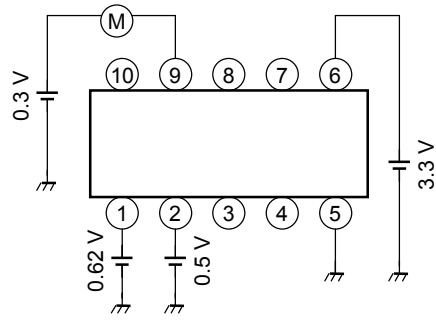
(5) DIFF-AMP
Low pass filter cut-off freq. **fc**



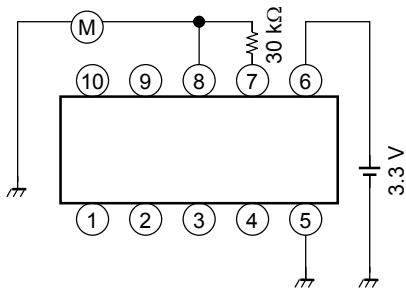
(6) DIFF-AMP
Output source current I_{Bso}



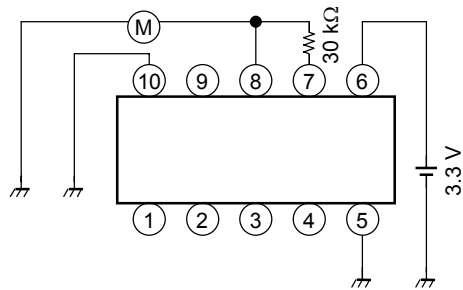
(7) DIFF-AMP
Output sink current I_{Bsi}



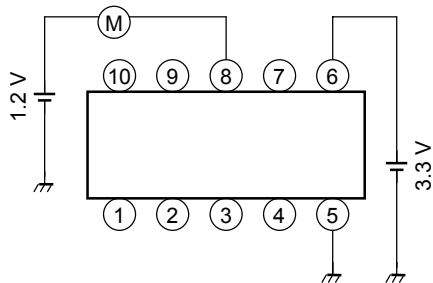
(8) OP-AMP
Input voltage 1 V_{in1}



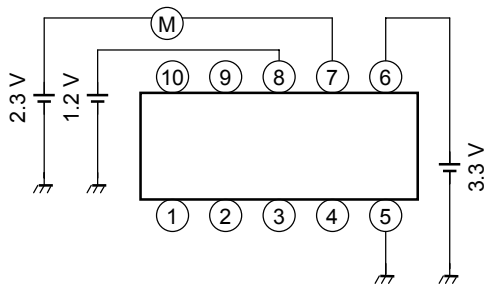
(9) OP-AMP
Input voltage 2 V_{in2}



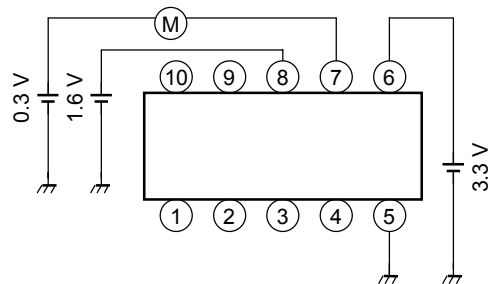
(10) OP-AMP
Input current I_{in}



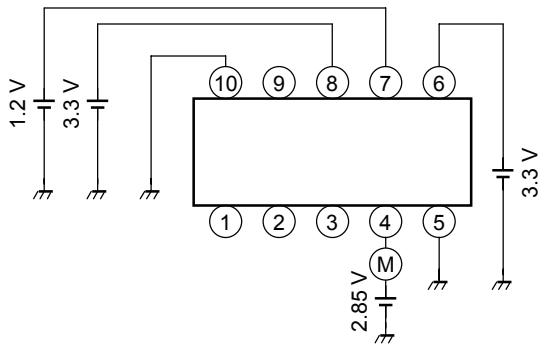
(11) OP-AMP
Output source current I_{Aso}



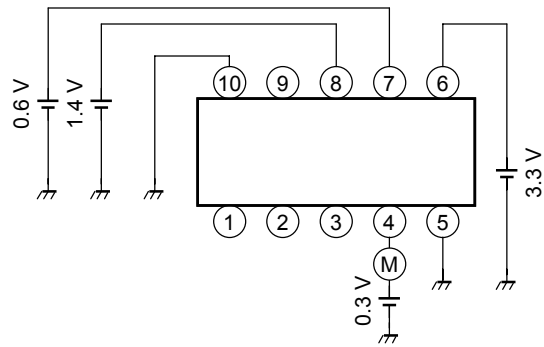
(12) OP-AMP
Output sink current I_{Asi}



(13) Window comparator
Output source current I_{Wso}

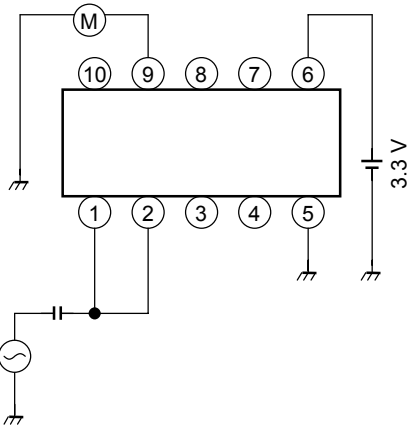


(14) Window comparator
Output sink current I_{Wsi}

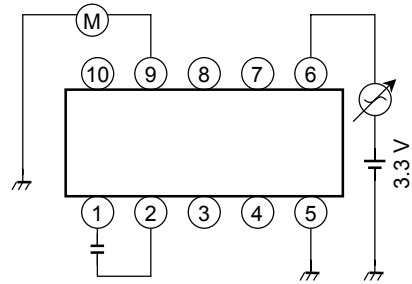


Test Circuit (for reference)

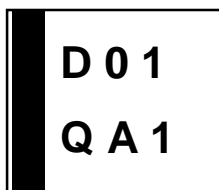
(a) DIFF-AMP
CMRR



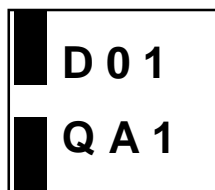
(b) DIFF-AMP
PSRR



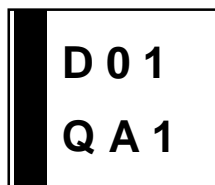
Marking



Week 1-26



Week 27-53



D01: Product number
Q: Monthly and Weekly code
A1: Lot code

Mold material: Epoxy resin

Lead material and disposition: An alloy of copper, soldering

Production country: JAPAN

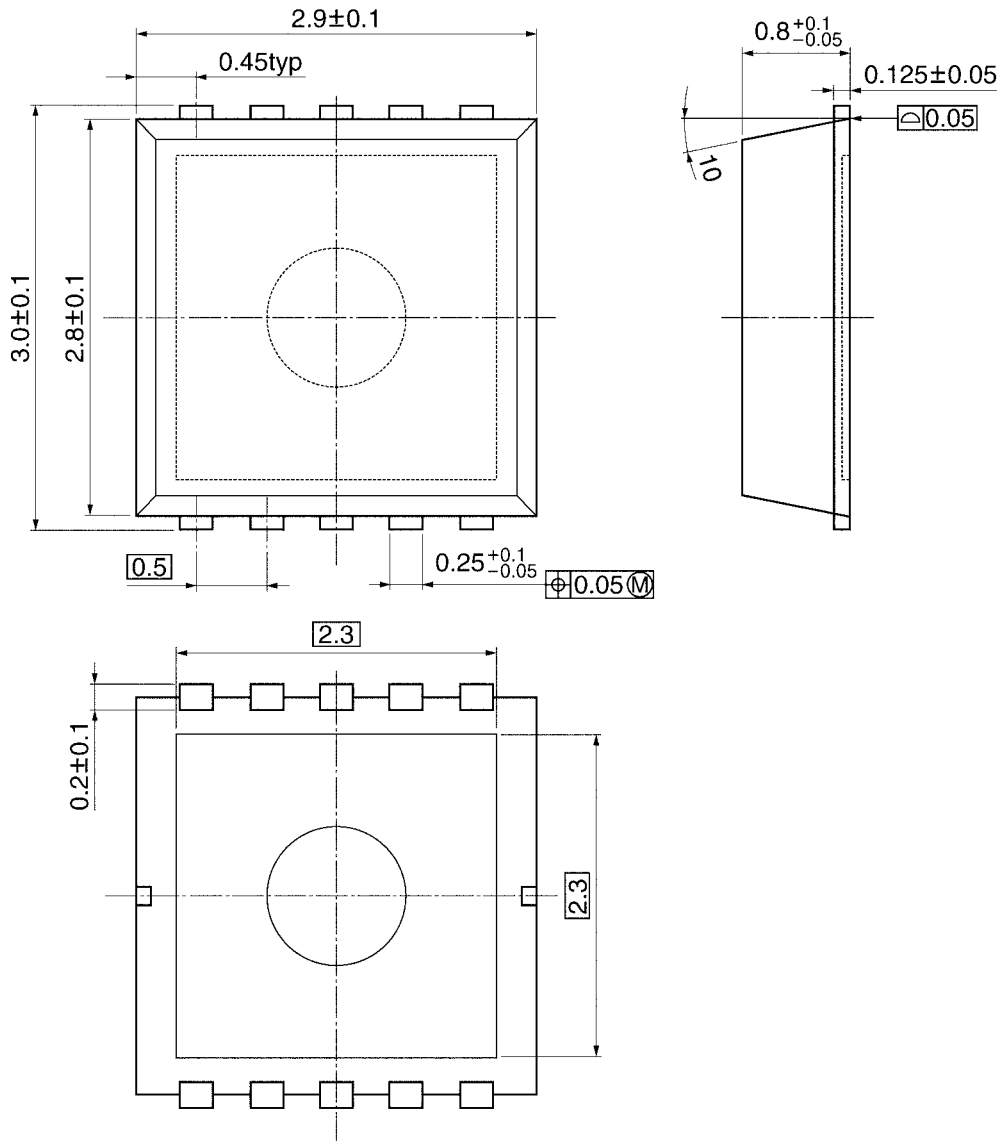
Production factory: Front end process TOSHIBA Kitakyushu factory

Back end process TOSHIBA Kitakyushu factory

Package Dimensions

SON10-P-0303-0.50

Unit: mm



Weight: 0.016 g (typ.)

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000707EBA

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